Low-ohmic single-pole single-throw analog switch

Rev. 1 — 28 October 2013

Product data sheet

1. General description

The NX3L1G66-Q100 is a low-ohmic single-pole single-throw analog switch. It has two input/output terminals (Y and Z) and an active HIGH enable input pin (E). When E is LOW, the analog switch is turned off.

Schmitt trigger action at the enable input (E) makes the circuit tolerant to slower input rise and fall times. The NX3L1G66-Q100 allows signals with amplitude up to V_{CC} to be transmitted from Y to Z; or from Z to Y. Its low ON resistance (0.5Ω) and flatness (0.13Ω) ensures minimal attenuation and distortion of transmitted signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A exceeds 7500 V
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 4000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)



Applications 3.

- Cell phone
- PDA
- Portable media player

Ordering information 4.

Table 1. **Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
NX3L1G66GW-Q100	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1

Marking 5.

Marking codes^[1] Table 2.

Type number	Marking code
NX3L1G66GW-Q100	DL

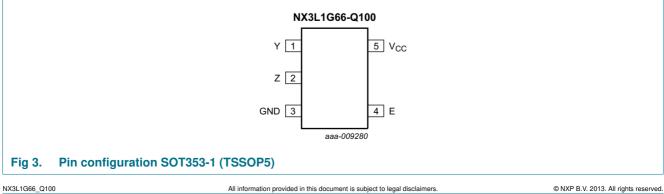
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

Functional diagram 6.



Pinning information 7.

7.1 Pinning



7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
Υ	1	independent input or output
Z	2	independent output or input
GND	3	ground (0 V)
E	4	enable input (active HIGH)
n.c.	-	not connected
V _{CC}	5	supply voltage

8. Functional description

Table 4.	Function table ^[1]	
Input E	Swite	h
L	OFF-	state
Н	ON-s	tate

[1] H = HIGH voltage level; L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					'
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	enable input E	<u>[1]</u> –0.5	+4.6	V
V _{SW}	switch voltage		<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_{l} < -0.5 V$	-50	-	mA
I _{SK}	switch clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	-	±50	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V _{SW} > -0.5 V or V _{SW} < V _{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For TSSOP5 package: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

10. Recommended operating conditions

Table 6.	Recommended operating conditions					
Symbol	Parameter	Conditions	Min	Max	Unit	
V _{CC}	supply voltage		1.4	4.3	V	
VI	input voltage	enable input E	0	4.3	V	
V _{SW}	switch voltage		[1] 0	V_{CC}	V	
T _{amb}	ambient temperature		-40	+125	°C	
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	[2] _	200	ns/V	

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current flows from terminal Y. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T _{ar}	_{nb} = 25	S°C	T _{amb} = ·	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V _{IH}	HIGH-level	V _{CC} = 1.4 V to 1.95 V	0.65V _{CC}	-	-	$0.65V_{CC}$	-	-	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	-	V
		V_{CC} = 3.6 V to 4.3 V	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	-	V
V _{IL}	LOW-level	V _{CC} = 1.4 V to 1.95 V	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	$0.35V_{CC}$	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	0.7	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.8	-	0.8	0.8	V
		$V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	$0.3V_{CC}$	V
I _I	input leakage current	enable input E; V ₁ = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μA
I _{S(OFF)}	OFF-state	Y port; see Figure 4							
	leakage current	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I _{S(ON)}	ON-state	Z port; see Figure 5							
	leakage current	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I _{CC}	supply current	$V_I = V_{CC} \text{ or GND};$ $V_{SW} = GND \text{ or } V_{CC}$							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA

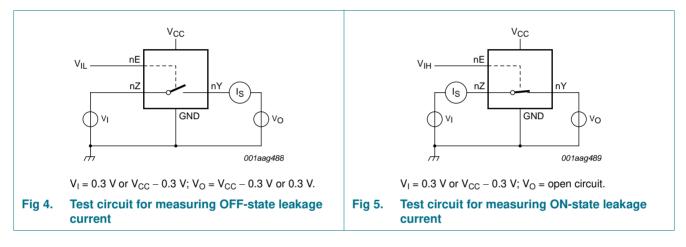
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Table 7. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	mbol Parameter Conditions		Ta	T _{amb} = 25 °C			T _{amb} = -40 °C to +125 °C		
			Min	Тур	Мах	Min	Max (85 °C)	Max (125 °C)	
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
$C_{S(ON)}$	ON-state capacitance		-	110	-	-	-	-	pF

11.1 Test circuits



11.2 ON resistance

Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

Symbol	Parameter	Conditions	$T_{amb} = -40 \degree C$ to +8		$T_{amb} = -40 \text{ °C to } +85 \text{ °C}$ $T_{amb} = -40 \text{ °C}$		C to +125 °C	Unit
-			Min	Typ <mark>[1]</mark>	Мах	Min	Max	-
R _{ON(peak)}	ON resistance (peak)	$V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see <u>Figure 6</u>						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		$V_{CC} = 1.65 V$	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω

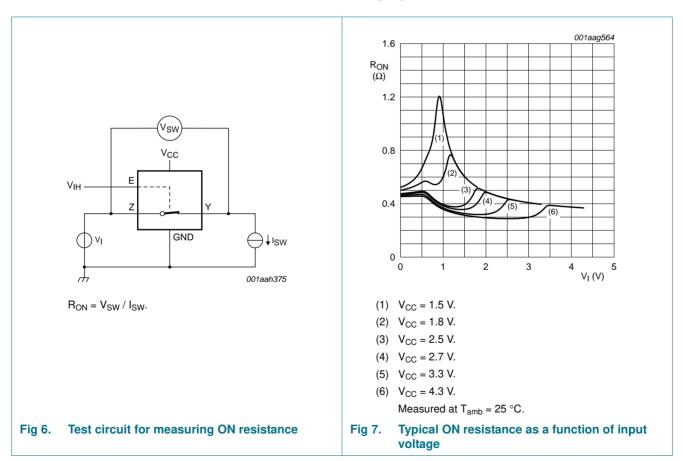
Table 8. ON resistance ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

Symbol	Parameter	Conditions	T _{amb} =	T _{amb} = -40 °C to +85 °C		$T_{amb} = -40$ °	Unit	
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R _{ON(flat)}	ON resistance (flatness)	$V_{I} = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$						
		V _{CC} = 1.4 V	-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		V _{CC} = 2.3 V	-	0.15	0.3	-	0.35	Ω
		V _{CC} = 2.7 V	-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$.

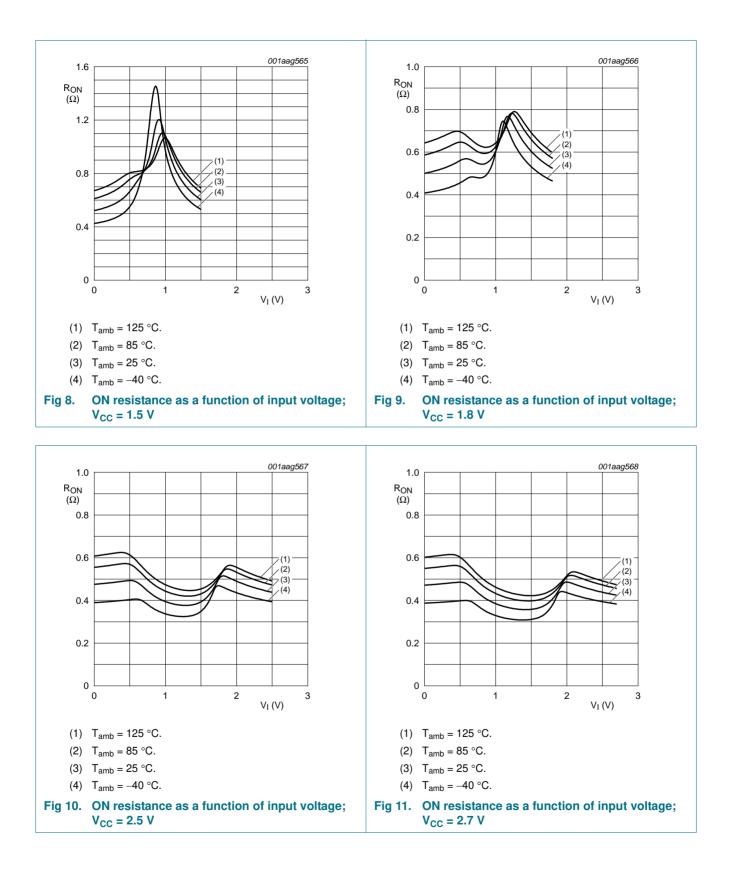
[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.



11.3 ON resistance test circuit and graphs

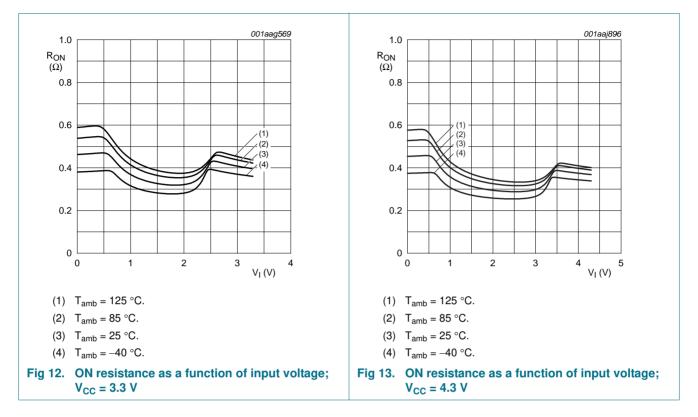
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Low-ohmic single-pole single-throw analog switch



NX3L1G66_Q100

Low-ohmic single-pole single-throw analog switch



12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit, see Figure 15.

Symbol	Parameter	Conditions	Та	_{mb} = 25	°C	T _{amb} = -	-40 °C to	+125 °C	Unit
			Min	Тур <u>[1]</u>	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	E to Z or Y; see Figure 14							
		$V_{CC} = 1.4 V$ to 1.6 V	-	27	41	-	43	48	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V	-	22	33	-	34	36	ns
		$V_{CC} = 2.3 \text{ V}$ to 2.7 V	-	17	26	-	27	30	ns
		$V_{CC} = 2.7 V \text{ to } 3.6 V$	-	14	23	-	24	26	ns
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	14	23	-	24	26	ns
t _{dis}	disable time	E to Z or Y; see Figure 14							
		V _{CC} = 1.4 V to 1.6 V	-	9	18	-	19	21	ns
		V _{CC} = 1.65 V to 1.95 V	-	7	13	-	15	16	ns
		$V_{CC} = 2.3 \text{ V}$ to 2.7 V	-	4	8	-	9	10	ns
		$V_{CC} = 2.7 V \text{ to } 3.6 V$	-	4	8	-	8	9	ns
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	4	8	-	8	9	ns

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

Low-ohmic single-pole single-throw analog switch

12.1 Waveform and test circuits

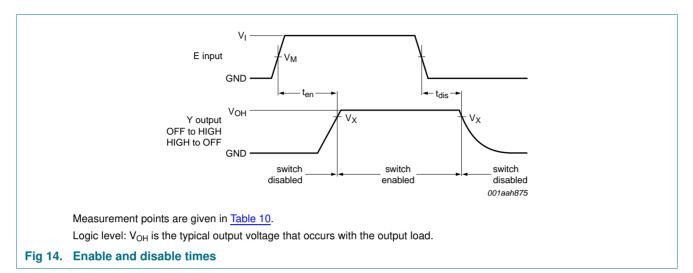


Table 10. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

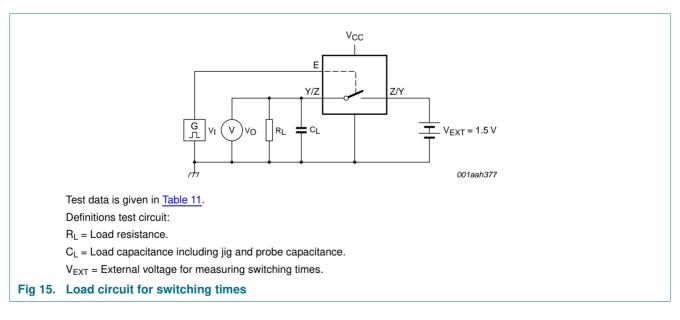


Table 11. Test data

Supply voltage	Input		Load	
V _{cc}	VI	t _r , t _f	CL	RL
1.4 V to 4.3 V	V _{CC}	≤ 2.5 ns	35 pF	50 Ω

12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

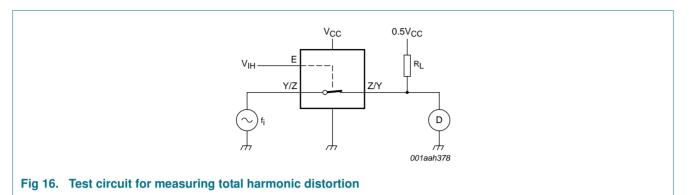
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns.

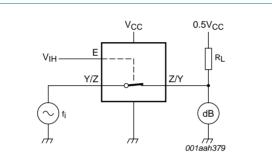
Symbol Param	Parameter	Conditions		T _{amb} = 25 °C			Unit
				Min	Тур	Max	
THD total harmonic distortion	f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see Figure 16	<u>[1]</u>					
	distortion	$V_{CC} = 1.4 \text{ V}; \text{ V}_{I} = 1 \text{ V} (p-p)$		-	0.15	-	%
	V _{CC} = 1.65 V; V _I = 1.2 V (p-p)		-	0.10	-	%	
		V _{CC} = 2.3 V; V _I = 1.5 V (p-p)		-	0.02	-	%
	V _{CC} = 2.7 V; V _I = 2 V (p-p)		-	0.02	-	%	
		V _{CC} = 4.3 V; V _I = 2 V (p-p)		-	0.02	-	%
f _(-3dB)	-3 dB frequency	$R_L = 50 \Omega$; see <u>Figure 17</u>	<u>[1]</u>				
response	response	V _{CC} = 1.4 V to 4.3 V		-	60	-	MHz
α_{iso} isolation (OFF-state)	$f_i = 100 \text{ kHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 18}}{100 \text{ kHz}}$	<u>[1]</u>					
	V _{CC} = 1.4 V to 4.3 V		-	-90	-	dB	
V _{ct} crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 19						
	V _{CC} = 1.4 V to 3.6 V		-	0.2	-	V	
	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	0.2	-	V	
Q _{inj} charge injection	$ f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; \\ R_{gen} = 0 \Omega; \text{see } \frac{\text{Figure 20}}{\text{Figure 20}} $						
		$V_{CC} = 1.5 V$		-	3	-	рС
		V _{CC} = 1.8 V		-	3	-	рС
		$V_{CC} = 2.5 V$		-	3	-	рС
		$V_{CC} = 3.3 V$		-	3	-	рС
		$V_{CC} = 4.3 V$		-	6	-	рС

[1] f_i is biased at 0.5V_{CC}.

Low-ohmic single-pole single-throw analog switch

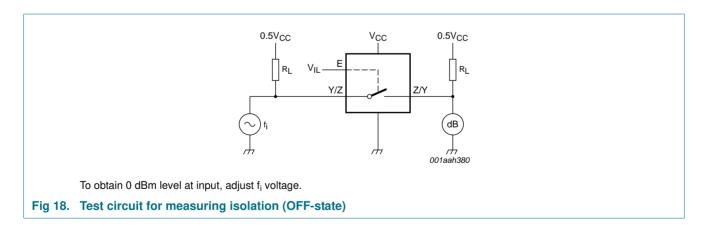
12.3 Test circuits



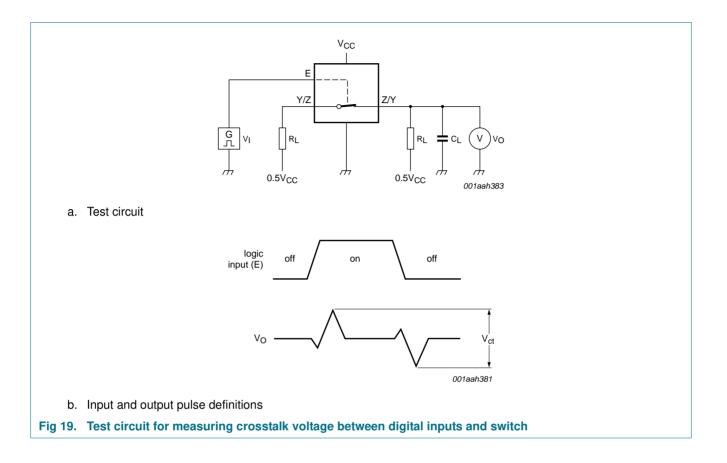


To obtain 0 dBm level at output, adjust fi voltage. Increase fi frequency until dB meter reads –3 dB.

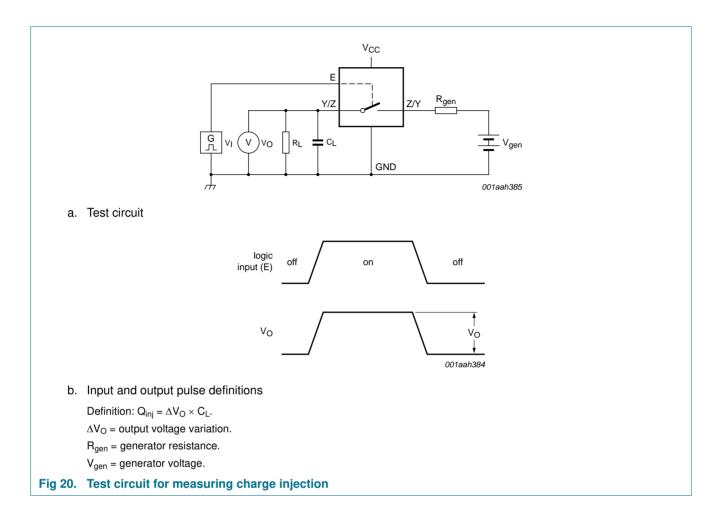
Fig 17. Test circuit for measuring the frequency response when channel is in ON-state



Low-ohmic single-pole single-throw analog switch



Low-ohmic single-pole single-throw analog switch



Low-ohmic single-pole single-throw analog switch

13. Package outline

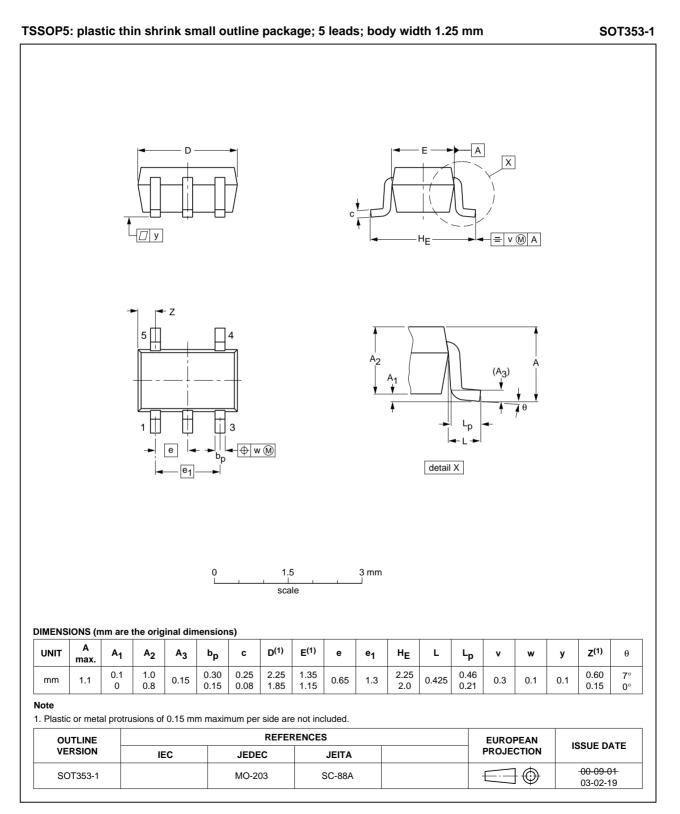


Fig 21. Package outline SOT353-1 (TSSOP5)

NX3L1G66_Q100

14. Abbreviations

Table 13. Abbreviations				
Acronym	Description			
CDM	Charged-Device Model			
CMOS	Complementary Metal-Oxide Semiconductor			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MIL	Military			
MM	Machine Model			
PDA	Personal Digital Assistant			
TTL	Transistor-Transistor Logic			

15. Revision history

Table 14. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1G66_Q100 v.1	20131028	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Low-ohmic single-pole single-throw analog switch

18. Contents

1	General description 1
2	Features and benefits 1
3	Applications 2
4	Ordering information 2
5	Marking 2
6	Functional diagram 2
7	Pinning information 2
7.1	Pinning 2
7.2	Pin description 3
8	Functional description 3
9	Limiting values 3
10	Recommended operating conditions 4
11	Static characteristics 4
11.1	Test circuits 5
11.2	ON resistance 5
11.3	ON resistance test circuit and graphs 6
12	Dynamic characteristics 8
12.1	Waveform and test circuits
12.2	Additional dynamic characteristics 10
12.3	Test circuits 11
13	Package outline 14
14	Abbreviations 15
15	Revision history 15
16	Legal information
16.1	Data sheet status 16
16.2	Definitions 16
16.3	Disclaimers
16.4	Trademarks 17
17	Contact information 17
18	Contents 18

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